**Vishay Semiconductors** 

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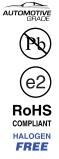


# **FEATURES**

- Silicon epitaxial planar diode
- Automotive graded device
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

# **APPLICATIONS**

· Extreme fast switches



# **MECHANICAL DATA**

Case: DO-35 Weight: approx. 125 mg Cathode band color: black Packaging codes/options: TR/10K per 13" reel (52 mm tape), 50K/box

TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE						
PART	ORDERING CODE	TYPE MARKING	INTERNAL CONSTRUCTION	REMARKS		
1N4148-P	1N4148-P-TAP or 1N4148-P-TR	V4148	Single diode	Tape and reel/ammopack		

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Reverse voltage		V <sub>R</sub>	75	V	
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	2	A	
Repetitive peak forward current		I <sub>FRM</sub>	500	mA	
Forward continuous current		I <sub>F</sub>	300	mA	
Average forward current	V <sub>R</sub> = 0	I <sub>F(AV)</sub>	150	mA	
Dewer dissinction	l = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW	
Power dissipation	l = 4 mm, T <sub>L</sub> ≤ 25 °C	P <sub>tot</sub>	500	mW	

<b>THERMAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	$I = 4 \text{ mm}, T_L = \text{constant}$	R <sub>thJA</sub>	350	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T <sub>stg</sub>	- 65 to + 150	°C	

Document Number: 81873

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# 1N4148-P



<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Forward voltage	I <sub>F</sub> = 10 mA	V <sub>F</sub>			1	V	
	V <sub>R</sub> = 20 V	I <sub>R</sub>			25	nA	
Reverse current	V <sub>R</sub> = 20 V, T <sub>j</sub> = 150 °C	I <sub>R</sub>			50	μA	
	V <sub>R</sub> = 75 V	I <sub>R</sub>			5	μA	
Breakdown voltage	$I_{R} = 100 \ \mu\text{A}, \ t_{p}/T = 0.01, \\ t_{p} = 0.3 \ \text{ms}$	V <sub>(BR)</sub>	100			V	
Diode capacitance	$V_{R} = 0 V, f = 1 MHz, V_{HF} = 50 mV$	C <sub>D</sub>			4	pF	
Rectification efficiency	V <sub>HF</sub> = 2 V, f = 100 MHz	η <sub>r</sub>	45			%	
Powerza racovery time	$I_F = I_R = 10 \text{ mA},$ $i_R = 1 \text{ mA}$	t <sub>rr</sub>			8	ns	
Reverse recovery time	$I_{F} = 10 \text{ mA}, V_{R} = 6 \text{ V}, \\ i_{R} = 0.1 \text{ x } I_{R}, R_{L} = 100 \Omega$	t <sub>rr</sub>			4	ns	

#### TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

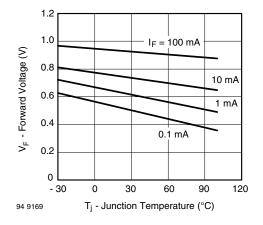


Fig. 1 - Forward Voltage vs. Junction Temperature

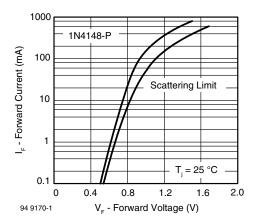


Fig. 2 - Forward Current vs. Forward Voltage

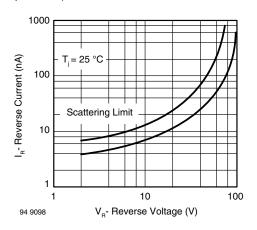


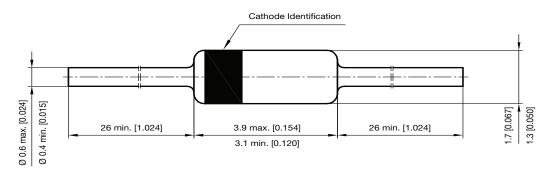
Fig. 3 - Reverse Current vs. Reverse Voltage

2



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# PACKAGE DIMENSIONS in millimeters (inches): DO-35



Rev. 6 - Date: 19. December 2011 Document no.: SB-V-3906.04-031(4) 94 9366



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